



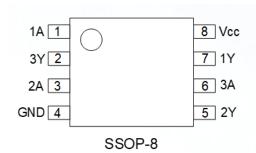
Description

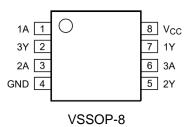
The 74LVC3G04 is a triple inverter gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Each of the inverters performs the positive Boolean function:

$$Y = \overline{A}$$

Pin Assignments





Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low-Power Consumption
- Ioff Supports Partial Power Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 2000V Human Body Model (A114)
 Exceeds 1000V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

- · Voltage-level shifting
- General-purpose logic
- · Power down signal isolation
- · Wide array of products such as:
 - · PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - · TV, DVD, DVR, set top boxes
 - Cell phones, personal navigation/GPS
 - · MP3 players, cameras, video recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

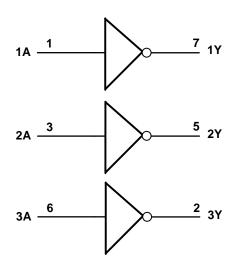
74LVC3G04 Document number: DS44928 Rev. 3 - 2 1 of 9 www.diodes.com



Pin Descriptions

Pin Name	Pin NO.	Description
1A	1	Data Input
3Y	2	Data Output
2A	3	Data Input
GND	4	Ground
2Y	5	Data Output
3A	6	Data Input
1Y	7	Data Output
Vcc	8	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Notes 4, 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or I _{OFF} State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} + 0.5	V
I _{IK}	Input Clamp Current V _I < 0	-50	mA
Iok	Output Clamp Current V _O < 0	-50	mA
lo	Continuous Output Current	±50	mA
I _{CC} , I _{GND}	Continuous Current Through V _{CC} or GND	±100	mA
TJ	Junction Temperature	+150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Recommended Operating Conditions (Note 6)

Symbol	Parameter	Conditions	Min	Max	Unit	
\/	Operating Voltage	Operating	1.65	5.5	V	
Vcc	Operating Voltage	Data Retention Only	1.5	_	V	
		Vcc = 1.65V to 1.95V	0.65 X Vcc	_		
.,	Link Lovel Innet Voltage	Vcc = 2.3V to 2.7V	1.7	_	V	
ViH	High-Level Input Voltage	Vcc = 3V to 3.6V	2	_	V	
		V _{CC} = 4.5V to 5.5V	0.7 X Vcc	_		
		V _{CC} = 1.65V to 1.95V	_	0.35 X V _{CC}		
		Vcc = 2.3V to 2.7V	_	0.7	1 ,,	
VIL	Low-Level Input Voltage	Vcc = 3V to 3.6V	_	0.8	V	
		V _{CC} = 4.5V to 5.5V	_	0.3 X V _{CC}		
Vı	Input Voltage	_	0	5.5	V	
Vo	Output Voltage	-	0	Vcc	V	
	High-Level Output Current	V _{CC} = 1.65V	_	-4		
		Vcc = 2.3V	_	-8		
Іон		V 0V	_	-16	mA	
		Vcc = 3V	_	-24		
		Vcc = 4.5V	_	-32		
		Vcc = 1.65V	_	4		
		V _{CC} = 2.3V	_	8		
loL	Low-Level Output Current	Vcc = 3V	_	16	mA	
		VCC = 3V	_	24		
		$V_{CC} = 4.5V$	_	32		
		Vcc = 1.8V ± 0.15V, 2.5V ± 0.2V	_	20		
Δt/ΔV	Input Transition Rise or Fall Rate	Vcc = 1.65V to 2.7V	_	10	ns/V	
		Vcc = 2.7V to 5V	_	5		
TA	Operating Free-Air Temperature		-40	+125	°C	

Note:

6. Unused inputs should be held at $\ensuremath{V_{\text{CC}}}$ or Ground for device proper operation.



Electrical Characteristics

Cumbal	Parameter	T (0 III)	.,	-40°C to	+85°C	-40°C to +	-125ºC	Unit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		$I_{OH} = -100\mu A$	1.65V to 5.5V	V _{CC} - 0.1	_	V _{CC} - 0.1	_	
		I _{OH} = -4mA	1.65V	1.2	_	1.2	_	
V/	Lligh Lovel Output Voltage	Iон = -8mA	2.3V	1.9	_	1.9	_	V
Voн	High-Level Output Voltage	Iон = -16mA	3V	2.4	_	2.4	_	V
		Iон = -24mA	3٧	2.3	_	2.3	_	
		Iон = -32mA	4.5V	3.8	_	3.8	_	
		I _{OL} = 100μA	1.65V to 5.5V	_	0.1	_	0.1	V
	V Land And Outset Values	IoL = 4mA	1.65V	_	0.45	_	0.45	
		I _{OL} = 8mA	2.3V	_	0.3	_	0.3	
Vol	Low-Level Output Voltage	IoL = 16mA	- 3V	_	0.4	_	0.4	V
		I _{OL} = 24mA		_	0.55	_	0.55	
		I _{OL} = 32mA	4.5V	_	0.55	_	0.75	
lı	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	±5	_	±5	μA
loff	Power Down Leakage Current	V _I or V _O = 5.5V	0	_	±10	_	±10	μΑ
lcc	Supply Current	$V_I = 5.5V$ or GND, $I_0 = 0$	1.65V to 5.5V	_	10	_	10	μA
Δlcc	Additional Supply Current	Input at V _{CC} – 0.6 V	3V to 5.5V	_	500	_	500	μA
Cı	Input Capacitance	V _I = V _{CC} or GND	3.3V	_	3.5 (Typ)	_	_	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance Junction-to-Ambient	SSOP-8	Note 7	_	130	_	°C/W
ӨЈА	Thermal Resistance Junction-to-Ambient	VSSOP-8	Note 7	_	155	_	°C/W
0	Thermal Resistance Junction-to-Case	SSOP-8	Note 7	_	36	_	°C/W
Өлс	Thermal Resistance Junction-to-Case	VSSOP-8	Note 7	_	38	_	°C/W

Note: 7. Test condition: Device mounted on JEDEC 2s2p High-K board, FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

Operating Characteristics (T_A = +25°C, V_{CC} = 3.3V)

Symbol	Parameter	Test Conditions	V _{CC} = 1.8V	V _{CC} = 2.5V	V _{CC} = 3.3V	V _{CC} = 5V	Unit
Symbol	i didilietei	rest conditions	Тур	Тур	Тур	Тур	5111
CPD	Power Dissipation Capacitance	f = 10MHz 1 Input Switching	16	16	18	22	pF

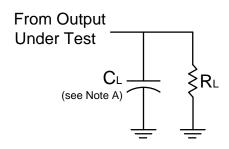


Switching Characteristics

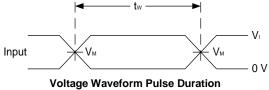
Figure 1

Parameter	From	То	Vcc	T _A = -40°C	to +85°C	T _A = -40°C	to +125°C	Unit
Parameter	Input	Output		Min	Max	Min	Max	Offic
			1.8V ± 0.15V	3.2	7.9	3.2	8.9	
4	۸		$2.5V \pm 0.2V$	1.5	4.4	1.5	5.4	
tPD	A Y	$3.3V \pm 0.3V$	1.4	4.1	1.4	5.1	ns	
			$5.0V \pm 0.5V$	1.1	3.2	1.1	3.8	

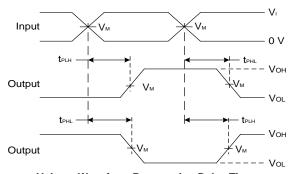
Parameter Measurement Information (Notes B, C, D)



Vcc	In	puts	V _M	CL	RL	
VCC	Vı	t _r /t _f	V IVI)L	INL	
1.8V ± 0.15V	Vcc	≤2ns	V _{CC} / 2	30pF	1kΩ	
2.5V ± 0.2V	Vcc	≤2ns	Vcc / 2	30pF	500Ω	
$3.3V \pm 0.3V$	3V	≤2.5ns	1.5V	50pF	500Ω	
5.0V ± 0.5V	Vcc	≤2.5ns	Vcc / 2	50pF	500Ω	







Voltage Waveform Propagation Delay Times Inverting and Noninverting Outputs

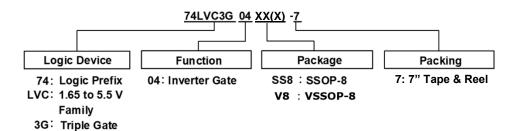
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
 C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .



Ordering Information



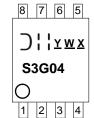
5 (1)		Basham Carla		Packing	
Part Number	Package Code	Package	Qty.	Carrier	
74LVC3G04SS8-7	SS8	SSOP-8	3000	7" Tape and Reel (Note 8)	
74LVC3G04V8-7	V8	VSSOP-8	3000	7" Tape and Reel (Note 8)	

Note: 8. The taping orientation is located on our website at http://www.diodes.com/package-outlines.html.

Marking Information

SSOP-8





Y: Year: 0 to 9

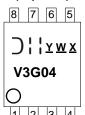
<u>W</u>: Week : A to Z : 1 to 26 week; a to z : 27 to 52 week; z represents

52 and 53 week X: Internal Code

Part Number	Package	Identification Code
74LVC3G04SS8-7	SSOP-8	S3G04

VSSOP-8

(Top View)



 $\underline{\underline{Y}}$: Year : 0 to 9 $\underline{\underline{W}}$: Week : A to Z : 1 to 26 week;

a to z : 27 to 52 week; z represents 52 and 53 week

X: Internal Code

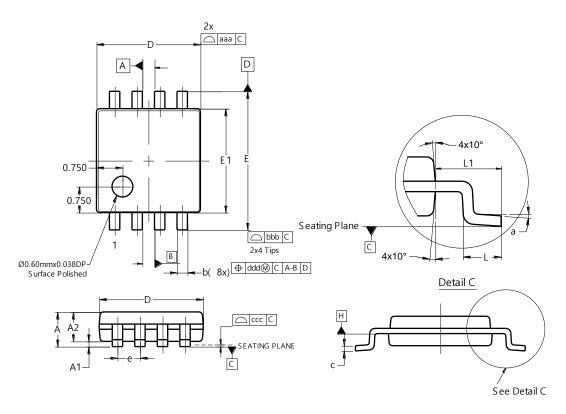
Part Number	Package	Identification Code
74LVC3G04V8-7	VSSOP-8	V3G04



Package Outline Dimensions

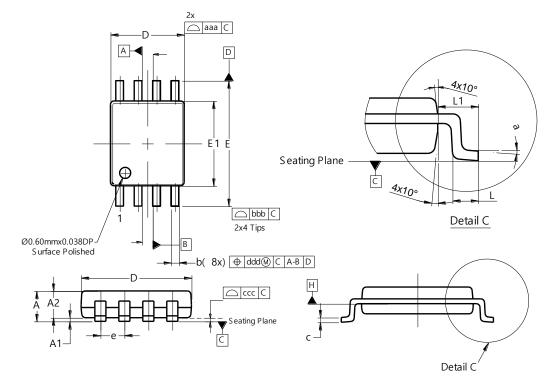
Please see http://www.diodes.com/package-outlines.html for the latest version.

SSOP-8



SSOP-8				
Dim	Min	Max	Тур	
A	-	1.30		
A1	0.05	0.15		
A2	0.95	1.20	1.05	
b	0.15	0.30	0.225	
C	0.08	0.23		
ם	2.75	3.15	2.95	
Е	3.75	4.25	4.00	
E1	2.70	2.90	2.80	
e		-	0.65	
ш	0.20	0.60	0.40	
L1	0.525	0.675	0.60	
а	0°	8°	4°	
aaa	0.20			
bbb	0.25			
CCC	0.10			
ddd	0.13			
All Dimensions in mm				

VSSOP-8



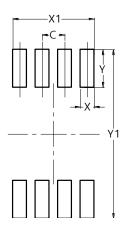
VSSOP-8				
Dim	Min	Max	Тур	
Α	0.60	0.90		
A 1		0.10		
A2	0.60	0.80		
b	0.17	0.25	0.21	
С	0.08	0.13		
D	1.90	2.10	2.00	
Е	3.20	3.60	3.40	
E1	2.20	2.40	2.30	
е			0.50	
L	0.30	0.40	0.35	
L1	0.50	0.60	0.55	
а	0°	6°	3°	
aaa	0.20			
bbb	0.25			
CCC	0.10			
ddd	0.13			
All Dimensions in mm				



Suggested Pad Layout

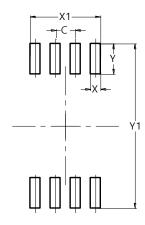
Please see http://www.diodes.com/package-outlines.html for the latest version.

SSOP-8



Dimensions	Value (in mm)
С	0.650
X	0.400
X1	2.350
Y	1.100
Y1	4.900

VSSOP-8



Dimensions	Value (in mm)	
С	0.500	
Х	0.250	
X1	1.750	
Y	0.750	
Y1	4 050	

Mechanical Data

SSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0169 grams (Approximate)

VSSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.011 grams (Approximate)



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